Supporting Information

Two-dimensional Halide Perovskites: Tuning Electronic Activities of Defects

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The line defects are modelled by a ribbon with width of ~ 3 nm (for edges) or 6 nm (for grain boundaries). For point defects in 2D Rb₂PbI₄, we use a 4x4 supercell (see the structure of the primitive cell in Fig. 1). For point defects in 2D MA₂SnBr₄, we use a 3x3 supercell to reduce the computational cost to an affordable limit.

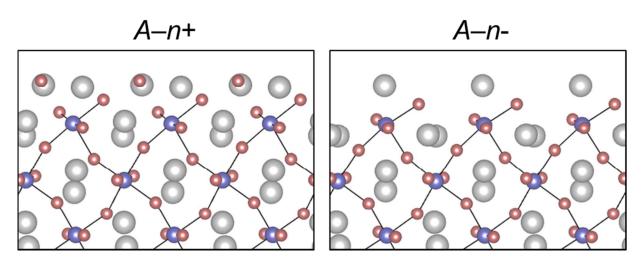


Fig. S1. Edges along *A* direction with surplus cations/deficient anions. A-n+ can be thought as adding more Rb into A-N+ (Fig. 2), and A-n- can be thought as removing I from A-N+, or adding more Rb into A-N- (Fig. 2).

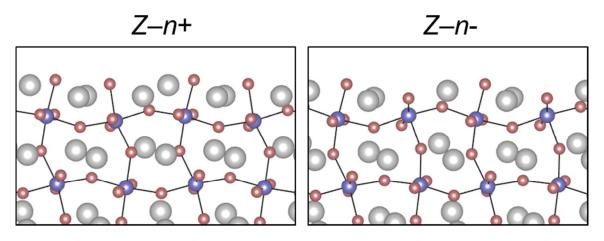


Fig. S2. Edges along Z direction with surplus cations/deficient anions. Z-n+ can be thought as adding more Rb into Z-N+ (Fig. 2), and Z-n- can be thought as removing I from Z-N+, or adding more Rb into Z-N- (Fig. 2).

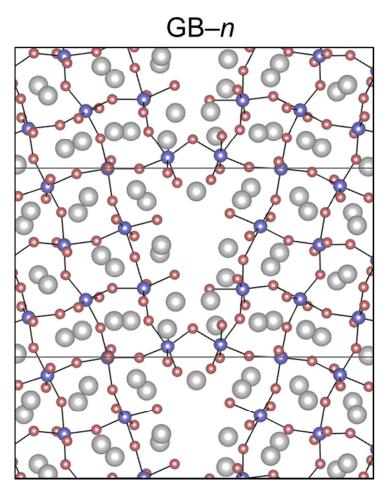


Fig. S3. Structure of grain boundary with surplus cations. This can be thought as adding more Rb into GB–N (Fig. 3).

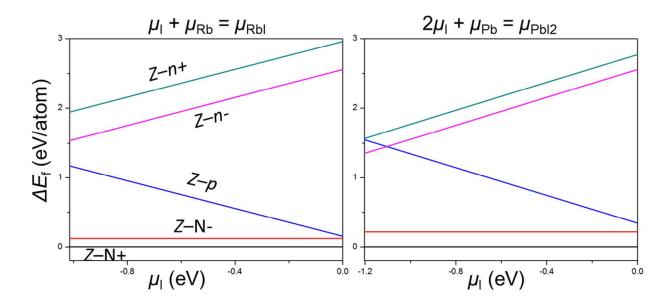


Fig. S4. Energies of various edges along Z direction, with respect to that of Z-N+, as a function of I chemical potential (with respect to that of I2 molecule) along phase boundaries.

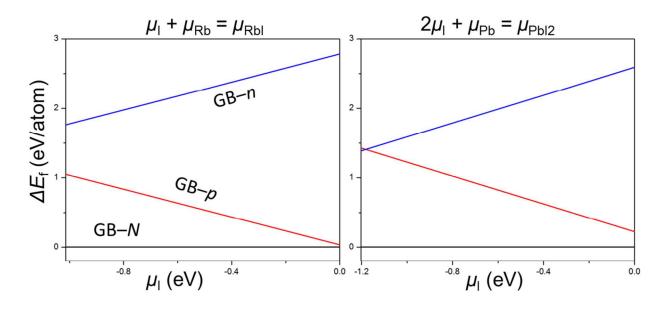


Fig. S5. Energies of various grain boundaries, with respect to that of GB–N, as a function of I chemical potential (with respect to that of I2 molecule) along phase boundaries.

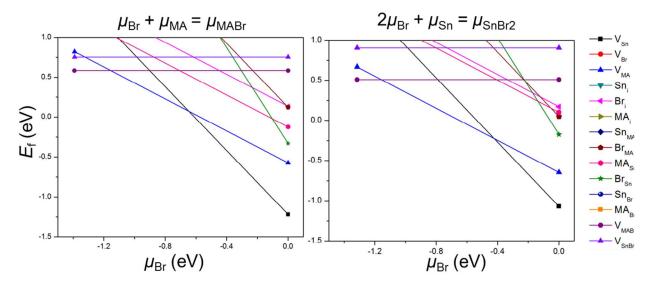


Fig. S6. Energies of various point defects in 2D MA_2SnBr_4 (MA= CH₃NH₃), as a function of Br chemical potential (with respect to that of Br₂ molecule) along phase boundaries. These suggest that the formation of harmful defects can be suppressed by decreasing the chemical potential of Br, in consistence with Rb₂PbI₄.